TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK3077A

VHF/UHF Band Amplifier Applications

Unit: mm

• Output power: $P_0 \ge 20.5 dBmW$

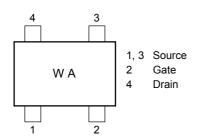
• Gain: $G_p \ge 10.5 dB$

• Drain Efficiency: $\eta D \ge 50\%$

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	10	V
Gate-source voltage	V_{GSS}	5	V
Drain current	I _D	0.1	Α
Power dissipation	P_{D}	0.1	W
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-45~150	°C

Marking



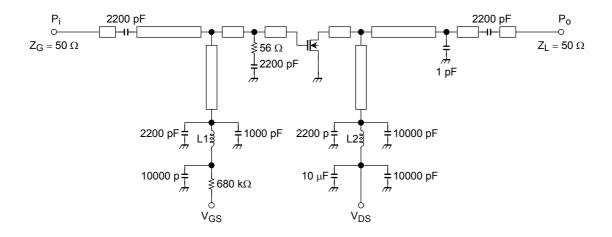
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output power	PO	V _{DS} = 4.5 V, lidle = 20 mA	20.5	_	_	dBmW
Drain efficiency	η _D	(V _{GS} = adjust)	50	_	_	%
Power gain	G _P	f = 470 MHz, P _i = 10dBmW	10.5	_	_	dB
Threshold voltage	V _{th}	V _{DS} = 4.8 V, I _D = 0.5 mA	0.25	_	1.25	V
Drain cut-off current	I _{DSS}	V _{DS} = 10 V, V _{GS} = 0 V	_	_	10	μA
Gate-source leakage current	I _{GSS}	V _{GS} = 5 V, V _{DS} = 0 V	_	_	5	μA
Load mismatch (Note 1) —	V_{DS} = 6.5 V, f = 470 MHz, P_i = 10dBmW, P_0 = 20.5dBmW (V_{GS} = adjust) VSWR LOAD 10:1 all phase	No degradation		_	

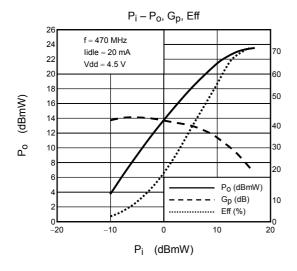
Caution: This transistor is the electrostatic sensitive device. Please handle with caution.

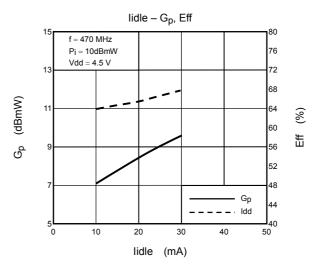
Note 1: When the RF output power test fixture is used

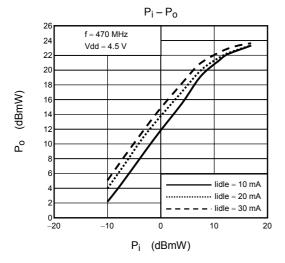
PF Output Power Test Fixture

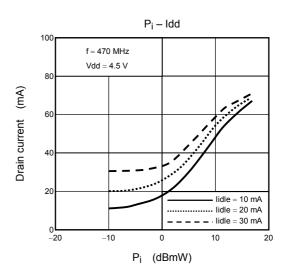


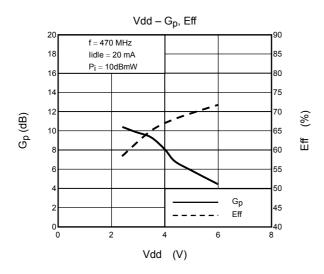
2 2002-01-09

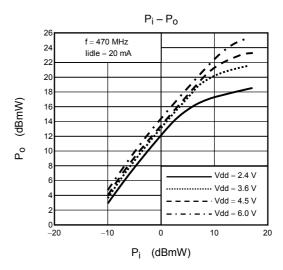




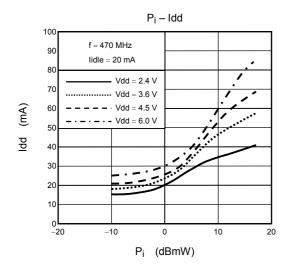








3



Caution: These are typical curves and devices are not necessarily guaranteed at these curves.

4

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.